

MOS FIELD EFFECT TRANSISTOR μ PA2200T1M

N-CHANNEL MOS FET FOR SWITCHING

DESCRIPTION

The μ PA2200T1M is N-channel MOS Field Effect Transistor designed for power management applications of portable equipments, such as load switch.

FEATURES

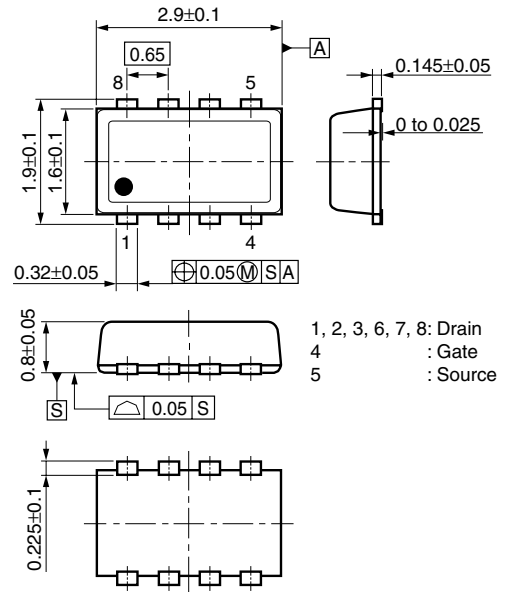
- Low on-state resistance
 $R_{DS(on)1} = 23 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 8 \text{ A)}$
 $R_{DS(on)2} = 31 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 4 \text{ A)}$
- Built-in gate protection diode
- 4.5 V Gate drive available

ORDERING INFORMATION

| PART NUMBER | PACKING | PACKAGE |
|---------------------------------------|----------------------|-------------------|
| μ PA2200T1M-T1-AT ^{Note} | 8 mm embossed taping | 8-pin VSOE (1629) |
| μ PA2200T1M-T2-AT ^{Note} | 3000 p/reel | 0.011 g TYP. |

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, All terminals are connected.)

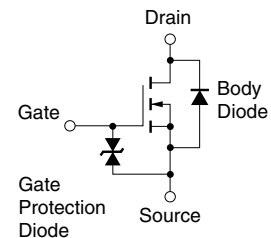
| | | | |
|---|----------------|-------------|------------------|
| Drain to Source Voltage ($V_{GS} = 0 \text{ V}$) | V_{DSS} | 30 | V |
| Gate to Source Voltage ($V_{DS} = 0 \text{ V}$) | V_{GSS} | ± 20 | V |
| Drain Current (DC) | $I_{D(DC)}$ | ± 8 | A |
| Drain Current (pulse) ^{Note1} | $I_{D(pulse)}$ | ± 32 | A |
| Total Power Dissipation ^{Note2} | P_{T1} | 1.1 | W |
| Total Power Dissipation ($PW = 5 \text{ sec}$) ^{Note2} | P_{T2} | 2.5 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

- Notes**
1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$
 2. Mounted on glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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EQUIVALENT CIRCUIT

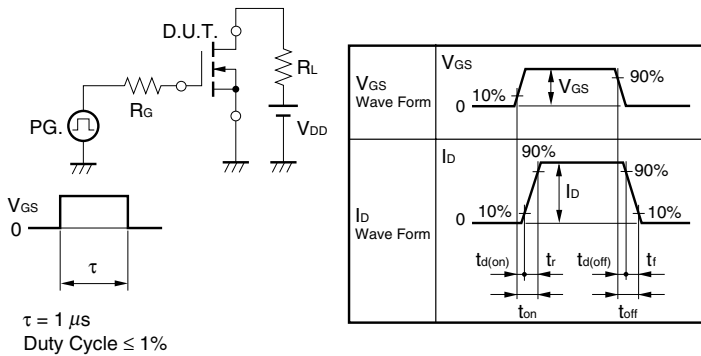


ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

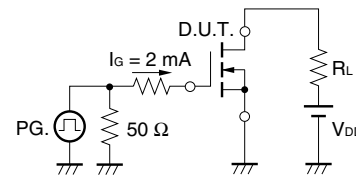
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---------------|---|------|------|----------|------------------|
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$ | | | 1 | μA |
| Gate Leakage Current | I_{GSS} | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | | | ± 10 | μA |
| Gate to Source Cut-off Voltage | $V_{GS(off)}$ | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$ | 1.0 | | 2.5 | V |
| Forward Transfer Admittance ^{Note} | $ y_{fs} $ | $V_{DS} = 10\text{ V}, I_D = 4\text{ A}$ | 3 | | | S |
| Drain to Source On-state Resistance ^{Note} | $R_{DS(on)1}$ | $V_{GS} = 10\text{ V}, I_D = 8\text{ A}$ | | 18 | 23 | $\text{m}\Omega$ |
| | $R_{DS(on)2}$ | $V_{GS} = 4.5\text{ V}, I_D = 4\text{ A}$ | | 23 | 31 | $\text{m}\Omega$ |
| Input Capacitance | C_{iss} | $V_{DS} = 10\text{ V},$ | | 870 | | pF |
| Output Capacitance | C_{oss} | $V_{GS} = 0\text{ V},$ | | 160 | | pF |
| Reverse Transfer Capacitance | C_{rss} | $f = 1\text{ MHz}$ | | 80 | | pF |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD} = 15\text{ V}, I_D = 4\text{ A},$ | | 9.2 | | ns |
| Rise Time | t_r | $V_{GS} = 10\text{ V},$ | | 3.4 | | ns |
| Turn-off Delay Time | $t_{d(off)}$ | $R_G = 10\ \Omega$ | | 31.7 | | ns |
| Fall Time | t_f | | | 5.3 | | ns |
| Total Gate Charge | Q_G | $V_{DD} = 24\text{ V},$ | | 8.7 | | nC |
| Gate to Source Charge | Q_{GS} | $V_{GS} = 5\text{ V},$ | | 3.0 | | nC |
| Gate to Drain Charge | Q_{GD} | $I_D = 8\text{ A}$ | | 3.2 | | nC |
| Body Diode Forward Voltage ^{Note} | $V_{F(S-D)}$ | $I_F = 8\text{ A}, V_{GS} = 0\text{ V}$ | | 0.85 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $I_F = 8\text{ A}, V_{GS} = 0\text{ V},$ | | 22 | | ns |
| Reverse Recovery Charge | Q_{rr} | $di/dt = 100\text{ A}/\mu\text{s}$ | | 15 | | nC |

Note Pulsed

TEST CIRCUIT 1 SWITCHING TIME

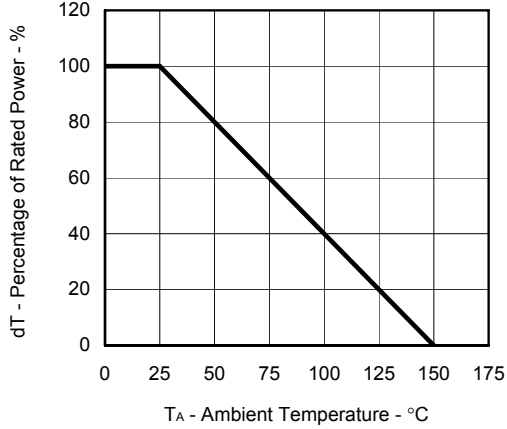


TEST CIRCUIT 2 GATE CHARGE

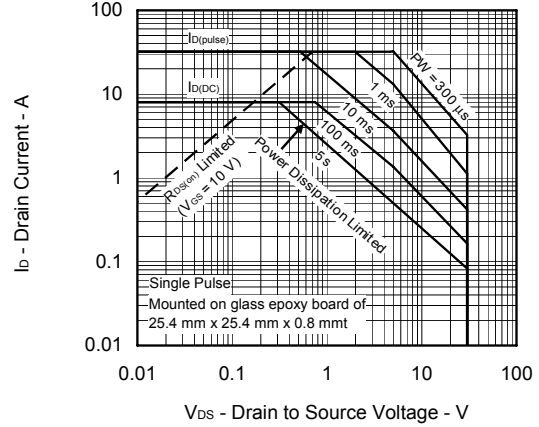


TYPICAL CHARACTERISTICS (T_A = 25°C)

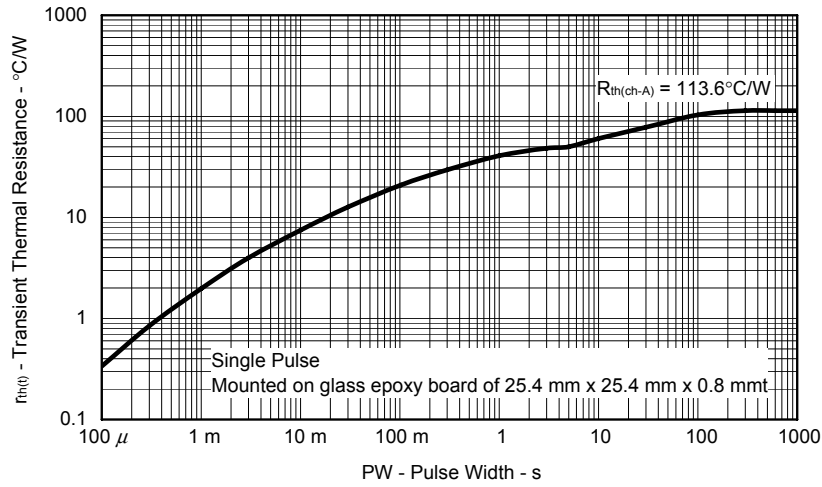
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



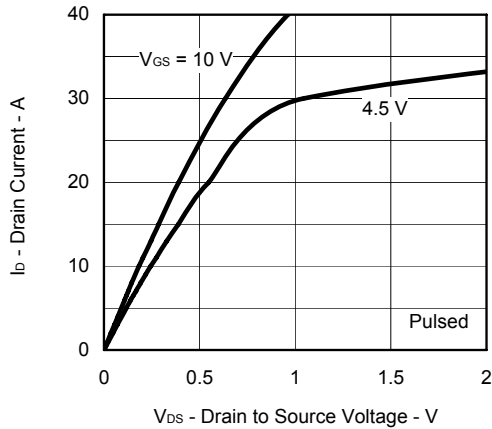
FORWARD BIAS SAFE OPERATING AREA



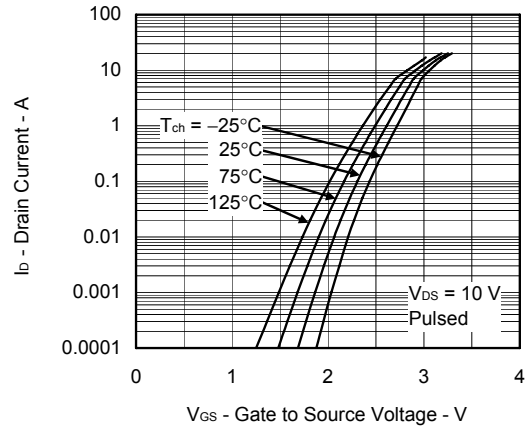
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



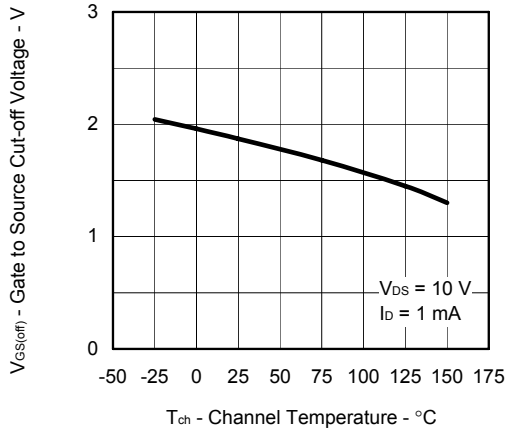
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



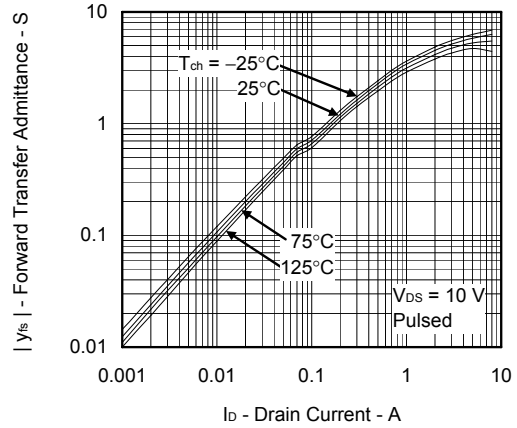
FORWARD TRANSFER CHARACTERISTICS



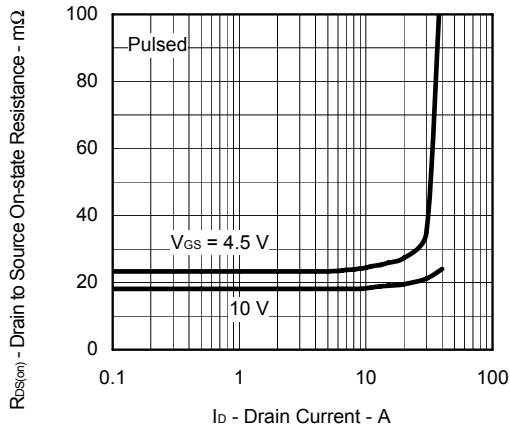
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



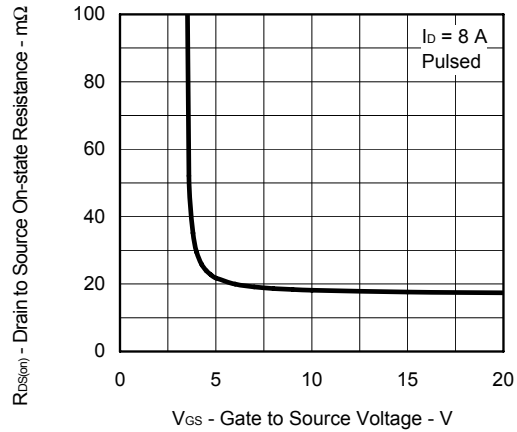
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



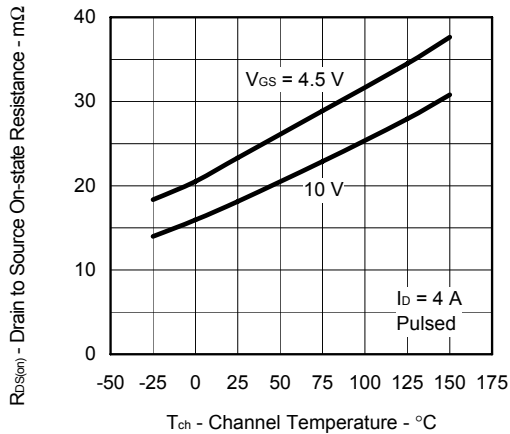
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



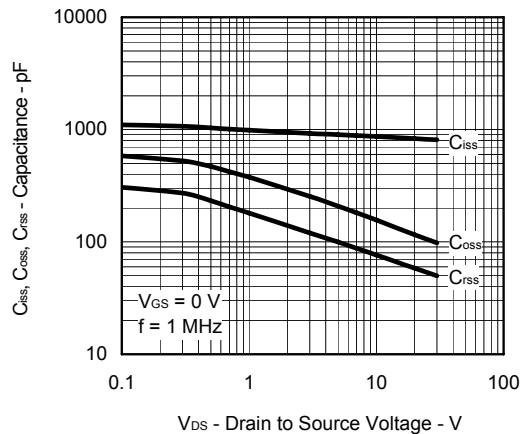
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



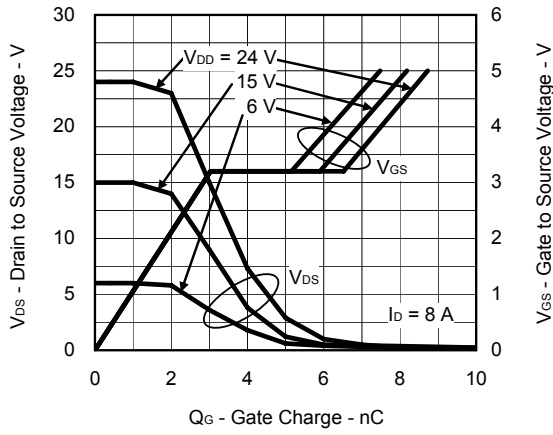
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



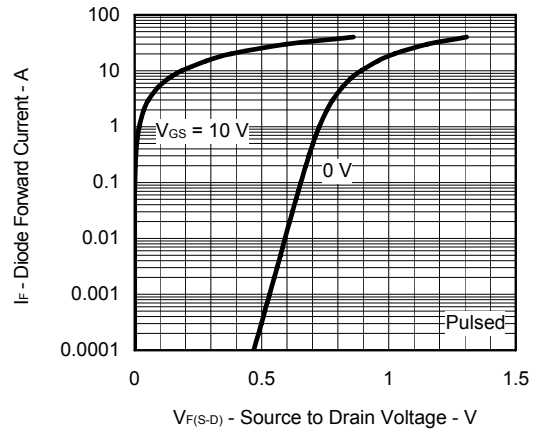
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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